

## CIR-S4SVSV2404G

DDR4 VLP SO-DIMM 2400MHz 4GB

### Description

This specification defines the electrical and mechanical requirements for 260 pin, 1.2 V (VDD), Double Data Rate, Synchronous DRAM Dual In-Line Memory Modules (DDR4 SDRAM SO-DIMM ). This DDR4 SO-DIMM is intended for use as main memory when installed in PCs, laptops and other systems.

Reference design examples are included which provide an initial basis for DDR4 SO-DIMM designs.

Modifications to these reference designs may be required to meet all system timing, signal integrity and thermal requirements for DDR4-2400 support. All DDR4 SO-DIMM implementations must use simulations and lab verification to ensure proper timing requirement and signal integrity in the design.

### Specifications

Density	4GB
Pin Count	260pin
Type	Unbuffered
Dimensions	69.60mm x 18.00mm
ECC	non-ECC
Component Config	512M x 8 bit
Data Rate	2400 MHz
CAS Latency	17
Voltage	1.2V
PCB Layers	8
Operating Temp.(TCASE)	0°C~+85°C
Module Ranks	Single Rank

### Features

- JEDEC Standard 260-pin Small Outline Dual In-Line Memory Module
- Inputs and Outputs are SSTL-12 compatible
- VDD=VDDQ = 1.2V±0.06V (1.14V~1.26V)
- Programmable CAS Latency(posted CAS): 11,12,13,14,15,16,17
- Low-Power auto self-refresh (LPASR)
- SDRAMs have 16 internal banks for concurrent operation (4 Bank Group of 4 banks each)
- Normal and Dynamic On-Die Termination for data, strobe and mask signals
- Data bus inversion (DBI) for data bus
- Fixed burst chop (BC) of 4 and burst length (BL) of 8 via the MRS
- Selectable BC4 or BL8 on-the fly (OTF)
- Fly-By topology
- Terminated control, command and address bus
- RoHS Compliant

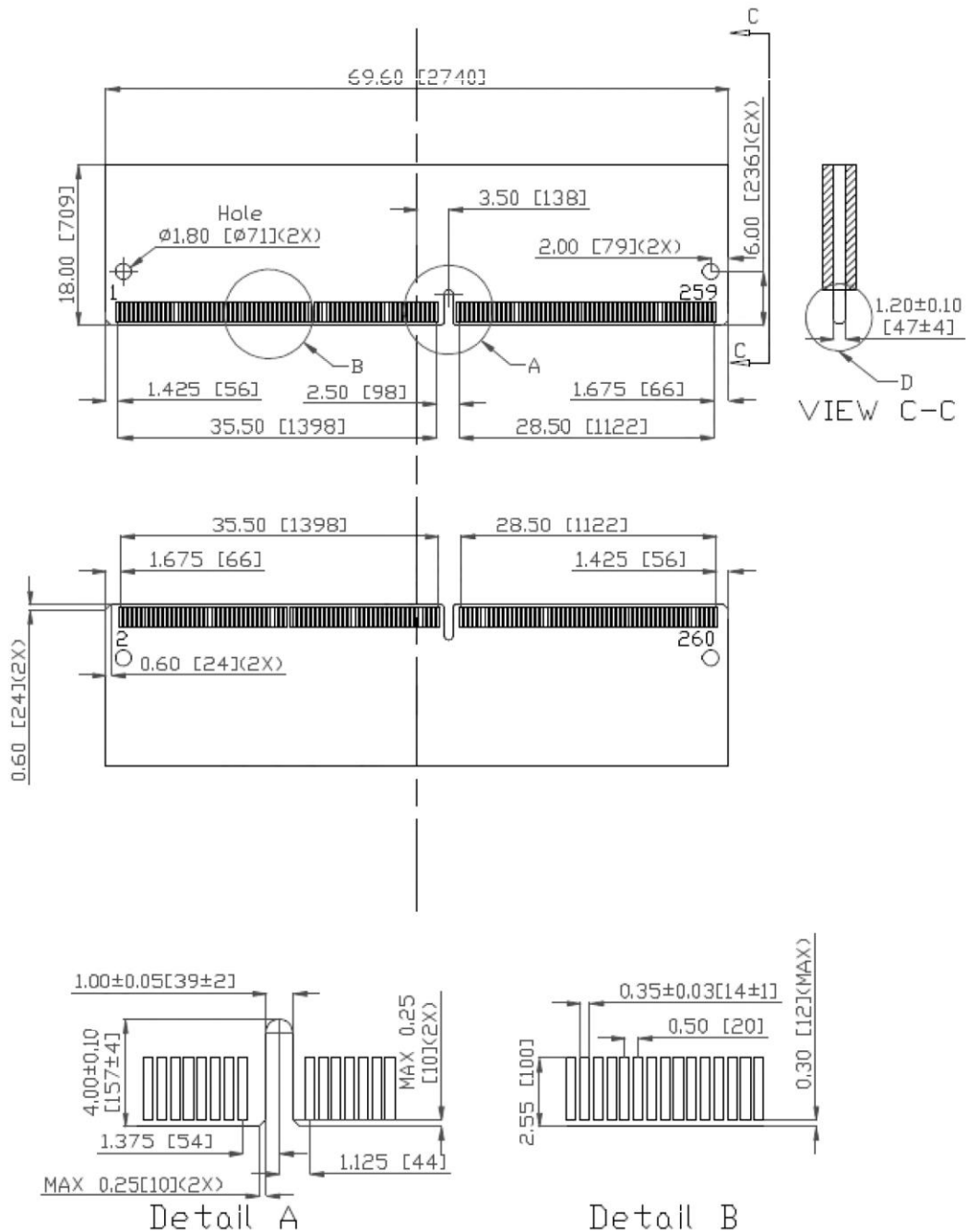


Speed Grade

Frequency Grade	Data Transfer Rate	CAS Latency Support							CL-tRCD-tRP
		CL11	CL12	CL13	CL14	CL15	CL16	CL17	
DDR4-2400	PC4-19200	1600	1600	1866	1866	2133	2133	2400	17-17-17

Package Dimensions

Unit: mm



Tolerances :  $\pm 0.15$ mm unless otherwise specified